Graphene: Applications in Thermal Management

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CPMT Panel Discussion – May 2015



Discovery of the Unique Heat Conduction Properties of Graphene



← IEEE Spectrum illustration of the first measurements of thermal conductivity of graphene carried out at UCR.

Details: A.A. Balandin et al., *Nano Letters*, 8, 902 (2008); A.A. Balandin, *Nature Mat.*, 10, 569 (2011).





Graphene Enhanced TIMs

Definitions: "graphene" vs. FLG vs. thin film of graphite



K.M.F. Shahil and A.A. Balandin, "Graphene - multilayer graphene nanocomposites as highly efficient thermal interface materials," *Nano Letters*, 12, 861 (2012).



Graphene TIMs with Strongly Enhanced Thermal Conductivity



K.M.F. Shahil and A.A. Balandin, "Graphene - multilayer graphene nanocomposites as highly efficient thermal interface materials," *Nano Letters*, 12, 861 (2012).

Independent Experimental Confirmation:



Y.-X. Fu et al. / International Journal of Thermal Sciences 86 (2014) 276-283



Testing C_nH_{2n+2} – Graphene Composites for PCM for Battery Thermal Management



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Time (min)



Thermal Conductivity of Graphene Laminate

Cooperation with Prof. Konstantin Novoselov and Bluestone Global Tech





H. Malekpour, K.-H. Chang, J.-C. Chen, C.-Y. Lu, D.L. Nika, K.S. Novoselov and A.A. Balandin, "Thermal conductivity of graphene 6 laminate," Nano Lett., 14, 5155–5161 (2014).

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Graphene *Quilts* for Thermal Management GaN Technology



GaN HFETs were used as examples of high-power density transistors; PMMA was utilized as the supporting membrane for graphene transfer to a desired location; the alignment was achieved with the help of a micromanipulator

Z. Yan, G. Liu, J.M. Khan and A.A. Balandin, Graphene-Graphite Quilts for Thermal Management of High-Power Transistors, *Nature Communications* **3**, 827 (2012).



Reduction of the Hot-Spot Temperature



The hot-spots temperature near drain contacts can be lowered by as much as ~ 20°C in such devices operating at ~13-W/mm – translates to an order of magnitude improvement in MTTF Alexander A. Balandin, University of California - Riverside



Thermal Properties of Copper Foils Coated with CVD Graphene







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- Schematic of the modified "laser (a) flash" experimental setup for measuring in-plane thermal diffusivity.
- Cu film coated with CVD (b) graphene placed on the sample holder.
- Back side of the sample holder (C) with the slits for measuring temperature.
- Raman spectrum of graphene (d) and few-layer graphene on Cu. The data is presented after background subtraction.

3000

(d)

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Thermal Properties of Graphene – Copper – Graphene Hetero-Films



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→ CVD of graphene on both sides of 9-µm-thick Cu films increases their thermal conductivity by 24% near room temperature.

→ Thermal resistance R=L/(KhW) of the additional heat conduction channel via graphene is much larger than via Cu film.

P. Goli, H. Ning, X. Li, C.Y. Lu, K.S. Novoselov and A.A. Balandin, Nano Letters, 14, 1497 (2014)



Enlargement of Cu Grain Size During CVD of Graphene



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Thermal conductivity K of a polycrystalline metal through that of a single-crystal metal:

 $K = (1 + \Lambda / D)^{-1} K_B$ $\frac{\tilde{D}}{D} = \frac{1 - (\Delta K / K)}{1 + (\Delta K / K)(D / \Lambda)}$

If one assumes that the average grain diameters are in the range D~1-10 μ m, the measured Δ K/K=0.2 can be achieved for if the ratio varies from ~0.13 to 0.016, which corresponds to the grains in reference Cu on the order of 130 – 160 nm.

P. Goli, H. Ning, X. Li, C.Y. Lu, K.S. Novoselov and A.A. Balandin, Thermal Properties of Graphene–Copper–Graphene Heterogeneous Films, Nano Letters, 14, 1497 (2014)



Graphene-on-Diamond: Carbon-on-Carbon Technology



Typical graphene FETs on SiO₂/Si reveal J_{BR} on the order of 10⁸ A/cm², which is ~100× larger than the limit for the metals but still smaller than the maximum achieved in CNTs Alexander A. Balandin, University of California - Riverside



Graphene Interconnects with Increased Breakdown Current Density



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Demonstration of the Aligned Graphene Fillers in Various Matrix Materials





Testing of Graphene-Enhanced TIMs in Computer CPUs

Only 1% of oriented graphene fillers in TIMs can reduce the CPU temperature by 10 °C. Filler orientation is achieved using special application pack in a process compatible with industry standards.





Take Home Messages

- Thermal conduction in 2D crystals is different from that in 3D bulk owing to specifics of long-wavelength phonon transport
- Thermal conductivity of the atomically thin films depends on the interplay of the intrinsic and extrinsic effects
- Graphene can be used as filler for thermal composites
- Graphene laminate can be used as thermal coating
- CVD graphene increases thermal conductivity of copper
- Graphene and FLG can be used as local heat spreaders
- Graphene is superior to CNTs owing to better matric coupling, lower cost and 2D geometry

 \rightarrow Thermal applications of graphene are much closer to commercialization than other applications of graphene

A.A. Balandin and D.L. Nika, *Materials Today*, **15** 266 (2012). A.A. Balandin, Nature Materials, 10, 569 - 581 (2011).



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